NSN 5962-01-356-8478

Memory Microcircuit - Page 1 of 1



-356-8478

| View Online at https://aerobasegroup.com/nsn/5962-01-356-8 |
|--|
| Operating Tempurature Range: |
| +0.0/+70.0 degrees celsius |
| Storage Tempurature Range: |
| -55.0/+125.0 degrees celsius |
| Features Provided: |
| High speed and low power and static operation and w/enable |
| Inclosure Material: |
| Ceramic or plastic |
| Inclosure Configuration: |
| Dual-in-line |
| Output Logic Form: |
| Complementary-metal oxide-semiconductor logic |
| Input Circuit Pattern: |
| 25 input |
| Current Rating Per Characteristic: |
| 80.00 milliamperes reverse current, dc absolute |
| Terminal Surface Treatment: |
| Solder |
| Voltage Rating And Type Per Characteristic: |
| -0.3 volts power source and 7.0 volts power source |
| Capitance Rating Per Characteristic: |
| 10.00 input picofarads and 10.00 output picofarads |
| Time Rating Per Chacteristic: |
| 150.00 nanoseconds access |
| Memory Device Type: |
| Ram |
| Terminal Type And Quantity: |
| 28 printed circuit |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| Yes - demil/mli |
| Fiig: |

A458a0